

Electronic Supplementary Information

Synergistic Optimization of Electronic and Lattice Structures through Ti-Intercalation and Se-Vacancy Engineering for High-Performance Aluminum Storage

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Experimental

Material synthesis:

Synthesis of MoSe₂ and Ti-MoSe₂: Sodium molybdate (0.52 g) and sulfuric acid (0.1 M, 3 mL) were added to deionized water (50 mL) during agitation. After that, titanium(IV) sulfate (0.024 g) was added to the solution. Besides, selenium powder (0.4 g) was dissolved in hydrazine hydrate (80%, 10 mL), after which the obtained solution was slowly added to the sodium molybdate solution and continuously agitated for 30 min. The resulting solution was transferred to a Teflon autoclave and held at 200 °C for 24 h. After cooling, the sediment was centrifugally washed with deionized water and ethanol, and then dried at 70 °C for 12 h in a vacuum oven to obtain the Ti-MoSe₂. Similarly, the MoSe₂ was prepared in the same method, except for the presence of titanium(IV) sulfate.

Synthesis of MoSe_{2-x} and Ti-MoSe_{2-x}: The Ti-MoSe₂ powder was transferred into a microwave oven under Ar atmosphere and radiated at 800 W for 15 s to obtain the Ti-MoSe_{2-x}. Similarly, MoSe_{2-x} is prepared in the same method, except that the raw material is MoSe₂ powder.

Material characterizations:

The X-ray diffraction (XRD, Rigaku Ultima IV) was used to characterize the crystal phase. The field-emission scanning electron microscopy (FESEM, JEOL JSM 7800F) and transmission electron microscopy (TEM, JEOL JEM F200) were performed to display the microstructure. The X-ray photoelectron spectroscopy (XPS, Kratos AXIS SUPRA+) was conducted to investigate the chemical state. The Raman spectra (LabRAM HR Evolution) with a 532 nm laser were used to detect the material structure. Electron paramagnetic resonance (EPR, EMXnano) tests were used to confirm the defects. The N₂ adsorption-desorption tests (ASAP 2420) were implemented to measure the surface area and pore size. The ICP-OES test (Agilent 720ES) was performed to determine the content.

Electrochemical measurements:

The batteries were assembled by Swagelok-type shells (Fig. S1) for electrochemical tests. The electrolyte was composed of aluminum chloride and 1-ethyl-3-methylimidazolium chloride mixed with a molar ratio of 1.3:1. The active material, acetylene black, and polyvinylidene difluoride were mixed in N-methyl pyrrolidone solvent with a mass ratio of 8:1:1 to obtain the cathode slurry. The slurry was coated on the surface of molybdenum foil after stirring for 24 h and then dried in a vacuum at 60 °C for 12 h. The load mass of the cathode was about 1.2 mg cm⁻². The aluminum foil and glass-fiber membrane served as anode and separator, respectively. The galvanostatic charge/discharge tests

of batteries were performed by the Land CT2001A system in the voltage range of 0.01 to 2.0 V. The cyclic voltammetry (CV) and electrochemical impedance spectroscopy were tested by a CHI 660E electrochemical workstation. The Tafel tests were performed using symmetrical cells at a voltage range from -0.2 to 0.2 V with 1.0 mV s^{-1} by CHI 660E electrochemical workstation.

Theoretical calculations:

The first-principles computations were employed by the Vienna Ab initio Simulation Package based on Density Functional Theory. The exchange-correlation energy of electrons was described using generalized gradient approximation with the Perdew-Burke-Ernzerhof parametrization. The core-valence interaction was performed using the Projector Augmented Wave method. The cut-off energy was 320 eV and the *k-point* mesh was set to be $3 \times 3 \times 1$. The energy convergence criteria were set to 10^{-5} eV.

Equation S1 for comparing Al³⁺ diffusion capability derived from the Randles–Sevcik equation.

$$I_{\text{peak}} = (2.69 \times 10^5) n^{1.5} S D_{\text{Al}^{3+}}^{0.5} C_{\text{Al}} \nu^{0.5} \quad \text{S1}$$

where the I_{peak} is the peak current, n is the charge transfer number, S is the area of the cathode, $D_{\text{Al}^{3+}}$ is the Al³⁺ diffusion coefficient, C_{Al} is the concentration of Al³⁺ in the cathode, and ν is the scan rate. The slope of the fitted curve ($I_{\text{peak}} / \nu^{0.5}$) represents the Al³⁺ diffusion rate as n , S , and C_{Al} are unchanged.

Equation S2 for evaluating capacitance-controlled and diffusion-controlled behaviors.

$$I_{\text{peak}} = k_1 \nu + k_2 \nu^{1/2} \quad \text{S2}$$

where the ratio of $k_1 \nu$ and $k_2 \nu^{1/2}$ refer to capacitance-controlled and diffusion-controlled behavior, respectively.

Equations S3 and S4 for comparing electronic diffusion capability.

$$D = \frac{R^2 T^2}{2 A^2 n^4 F^4 C^2 \sigma^2} \quad \text{S3}$$

$$Z' = R_{ct} + R_e \sigma \omega^{-1/2} \quad \text{S4}$$

where the R , T , A , n , F , C , δ refer to the gas constant, absolute temperature, area of the cathode, charge transfer number, Faraday constant, concentration of Al³⁺, and Warburg factor, respectively. The slope of the fitted curve ($Z' / \omega^{-1/2}$) mainly determines the diffusion coefficient (D) as other parameters are unchanged.

Equation S5 for calculating the Al³⁺ diffusion coefficient according to the GITT results.

$$D_{\text{Al}^{3+}} = \frac{4}{\pi \tau} \left(\frac{m_b V_m}{M_b S} \right)^2 \left(\frac{\Delta E_s}{\Delta E_\tau} \right)^2 \quad \text{S5}$$

where the τ , m_b , V_m , M_b , and S represent relaxation time, mass, molar volume, molar mass, and area of the cathode, respectively. The ΔE_s and ΔE_τ are voltage variations occurring in relaxation steps and the current pulse.

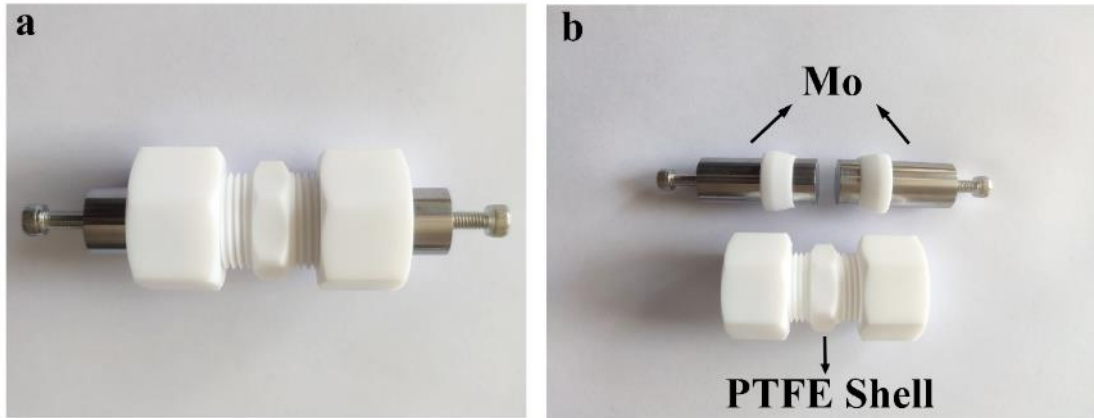


Fig. S1 Digital images of (a) Swagelok-type shell and (b) corresponding disassembled parts.

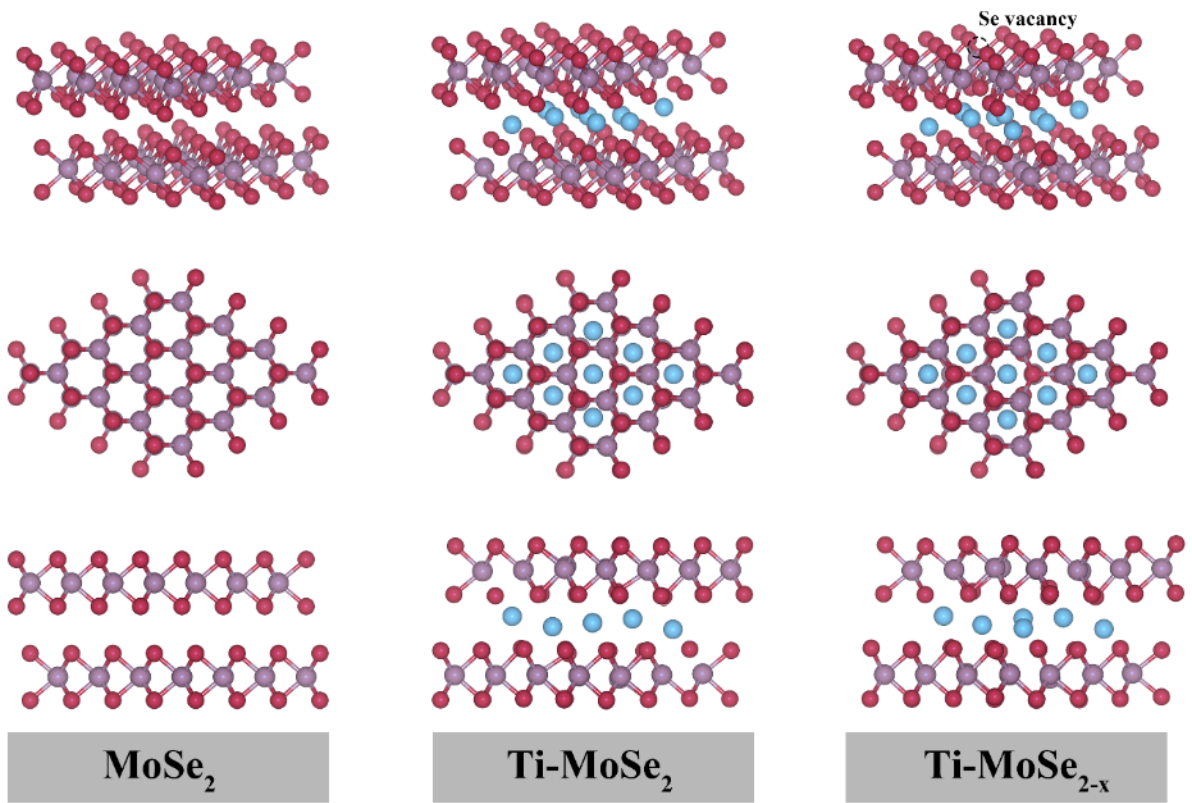


Fig. S2 Optimized structural models of MoSe₂, Ti-MoSe₂, and Ti-MoSe_{2-x}.

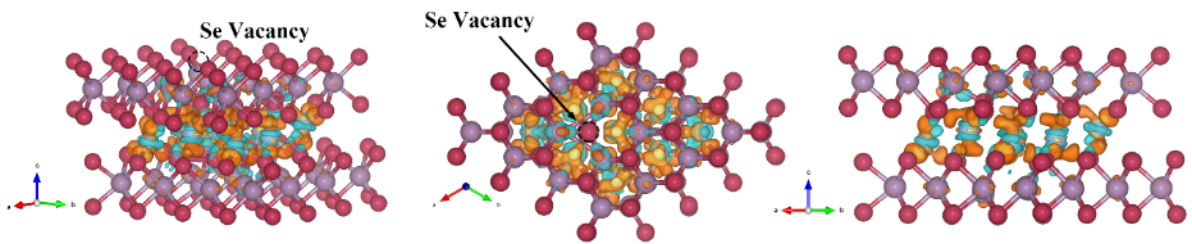


Fig. S3 Charge density difference of Ti-MoSe_{2-x}. The orange and blue regions represent charge accumulation and delocalization, respectively.

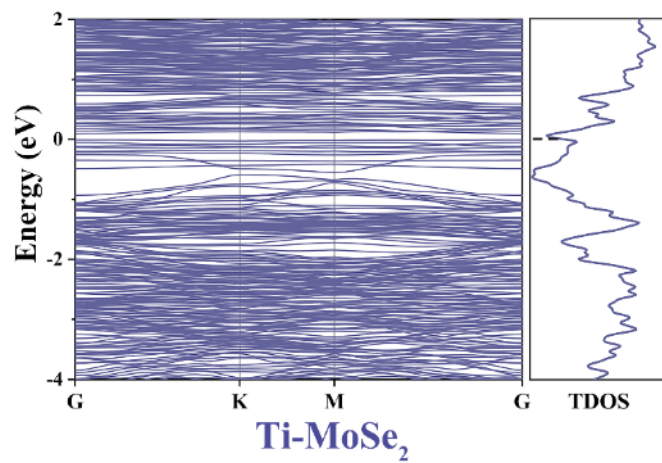


Fig. S4 Energy band structure of Ti-MoSe₂,

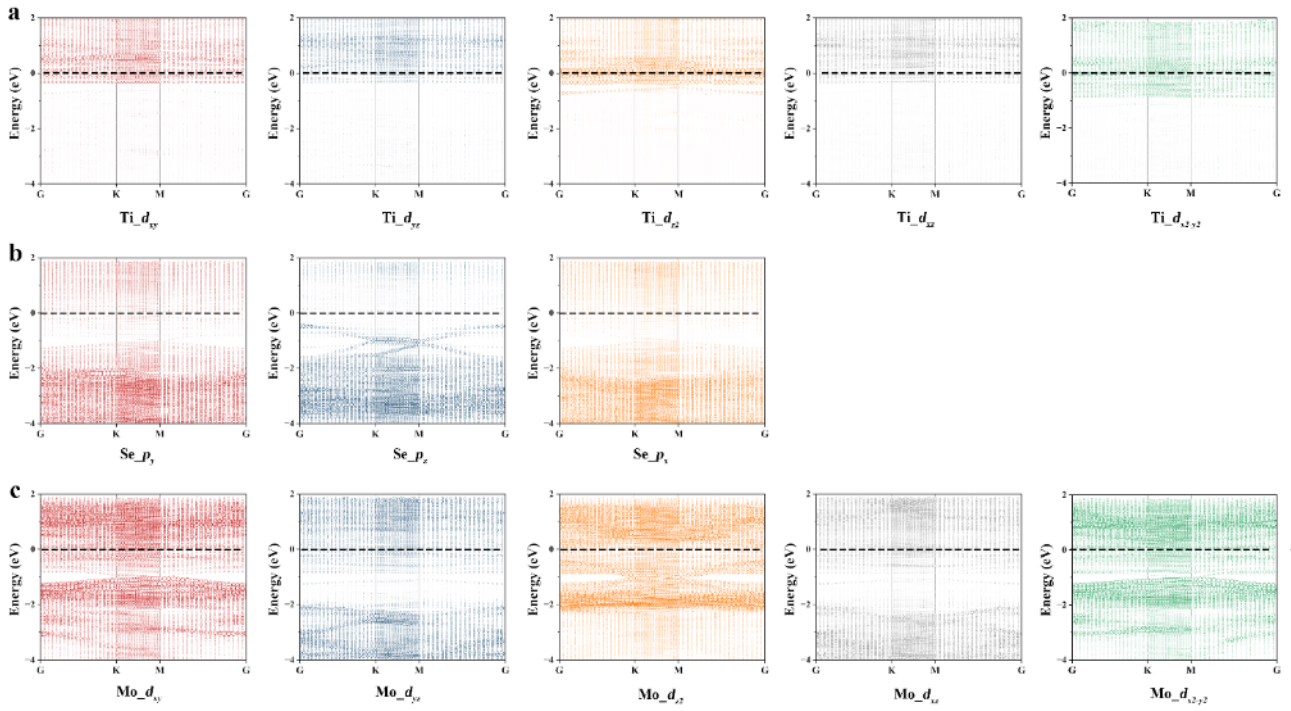


Fig. S5 Projected band of (a) Ti_3d, (b) Se_4p, and (c) Mo_4d orbitals in Ti-MoSe_{2-x}.

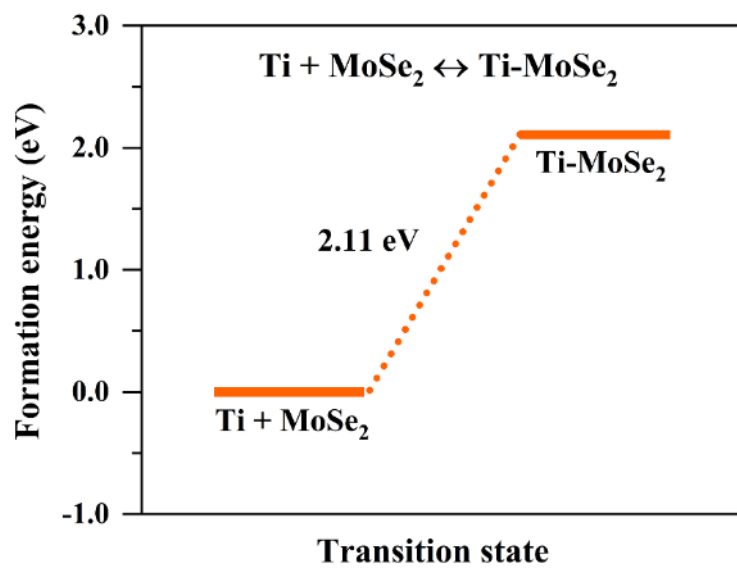


Fig. S6 Formation energy of Ti-MoSe₂.

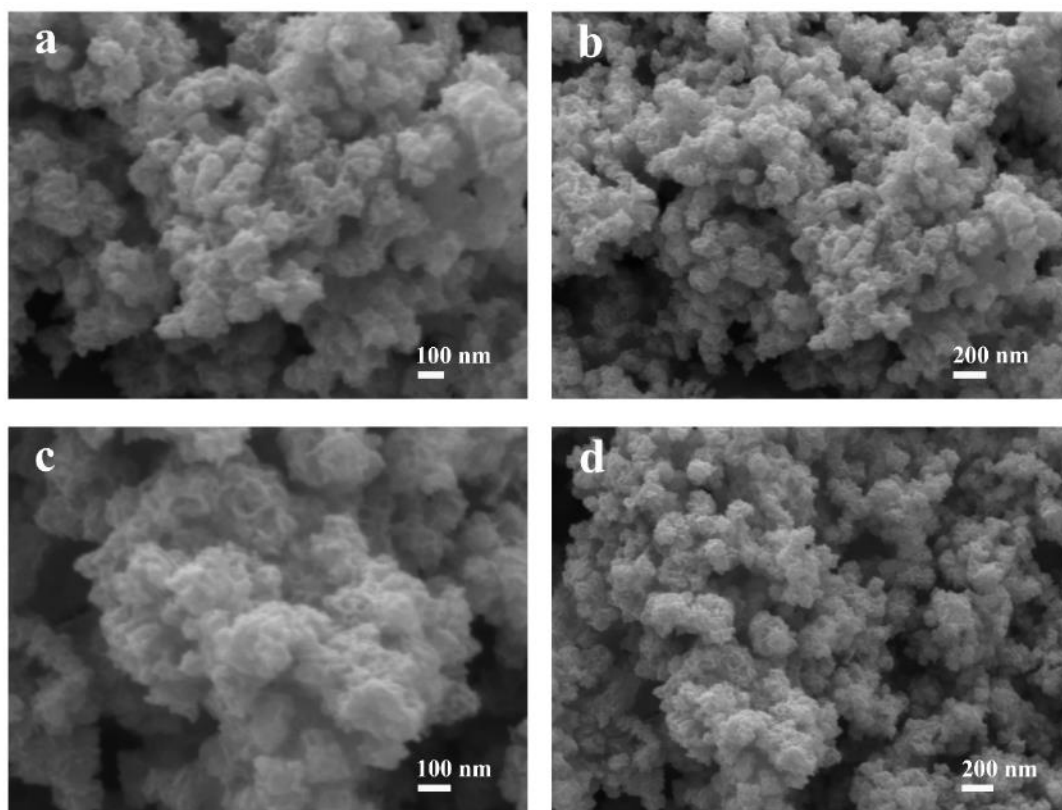


Fig. S7 FESEM images of MoSe₂.

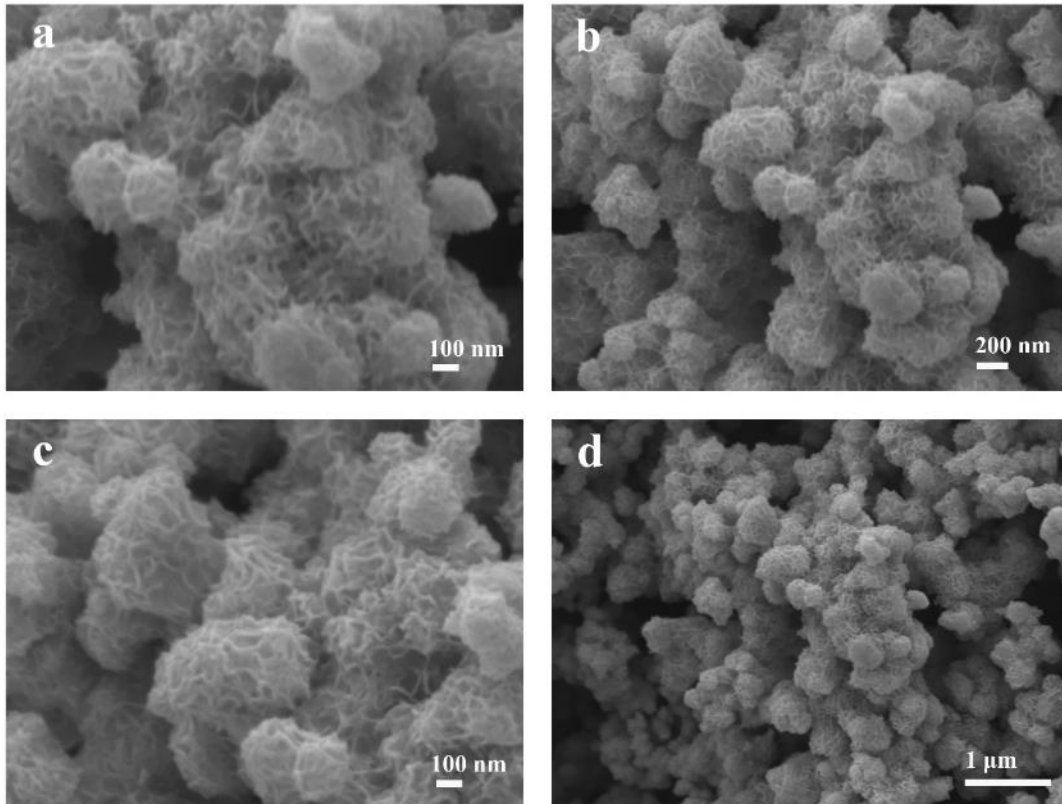


Fig. S8 FESEM images of Ti-MoSe₂.

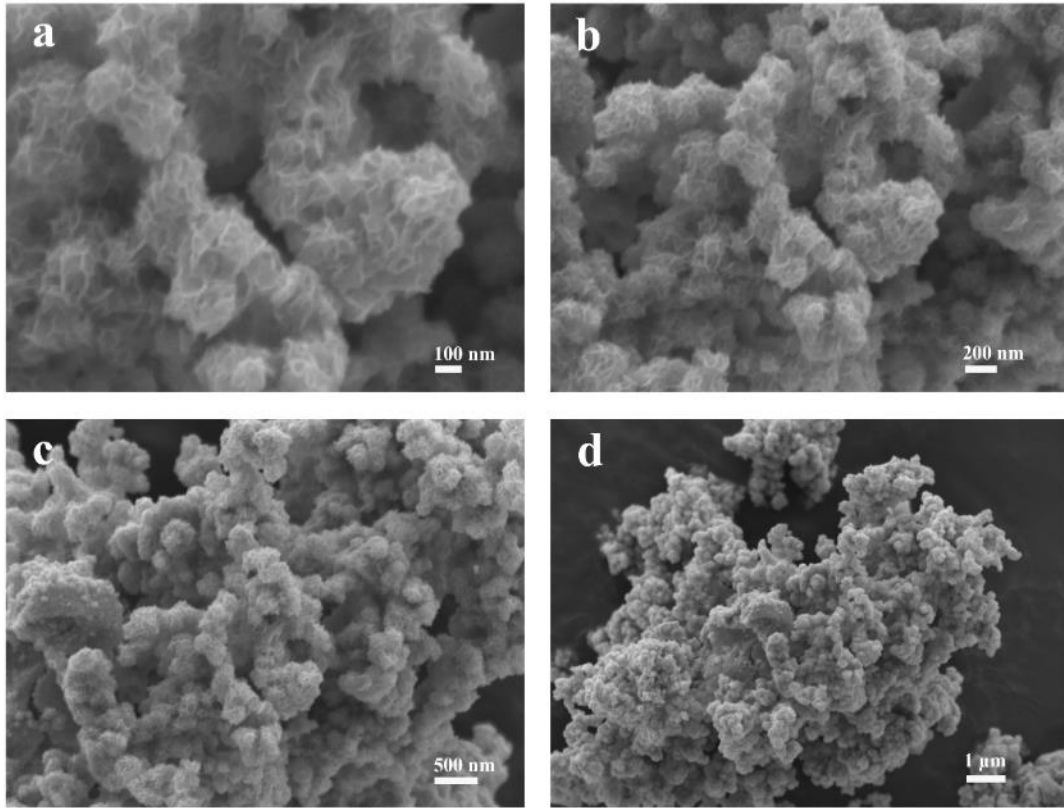


Fig. S9 FESEM images of Ti-MoSe_{2-x}.

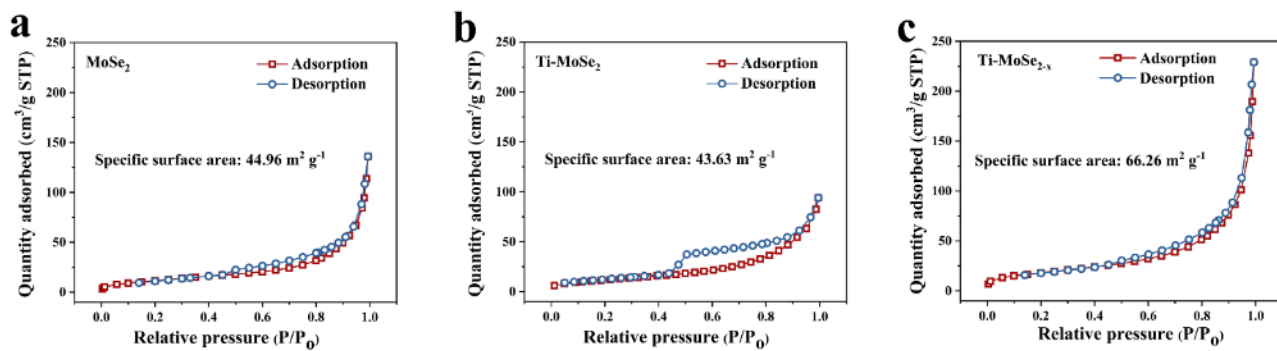


Fig. S10 Nitrogen adsorption/desorption isotherms of (a) MoSe₂, (b) Ti-MoSe₂, and (c) Ti-MoSe_{2-x}.

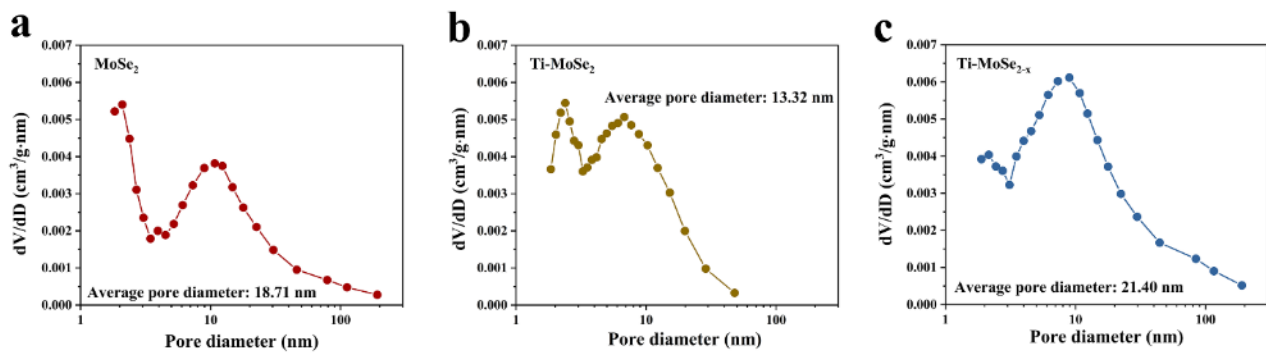


Fig. S11 Pore size distribution curves of (a) MoSe_2 , (b) Ti-MoSe_2 , and (c) Ti-MoSe_{2-x} .

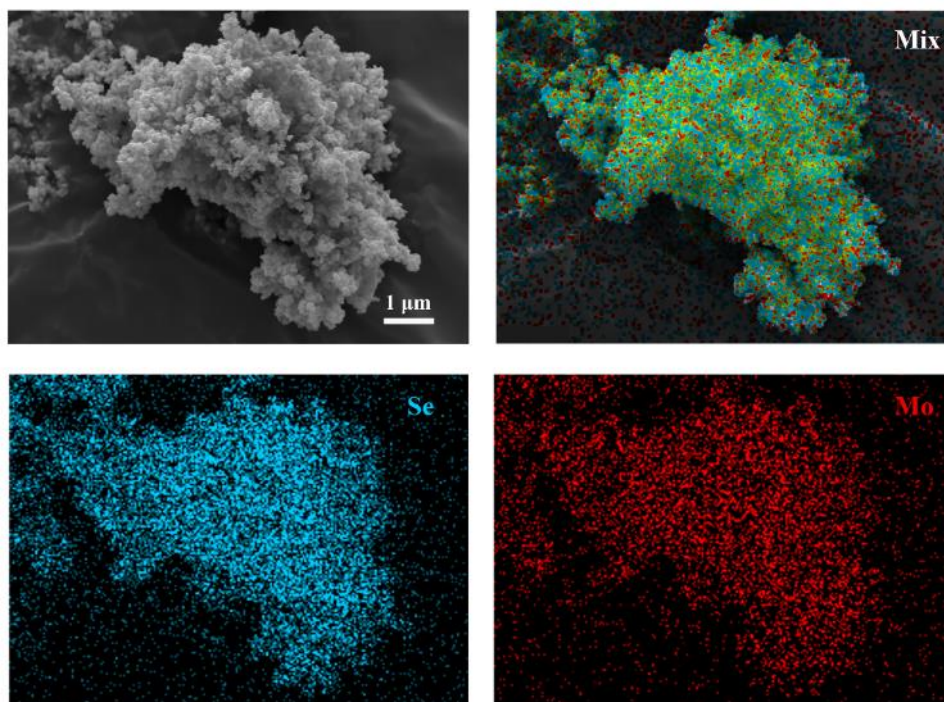


Fig. S12 EDX mappings of MoSe₂.

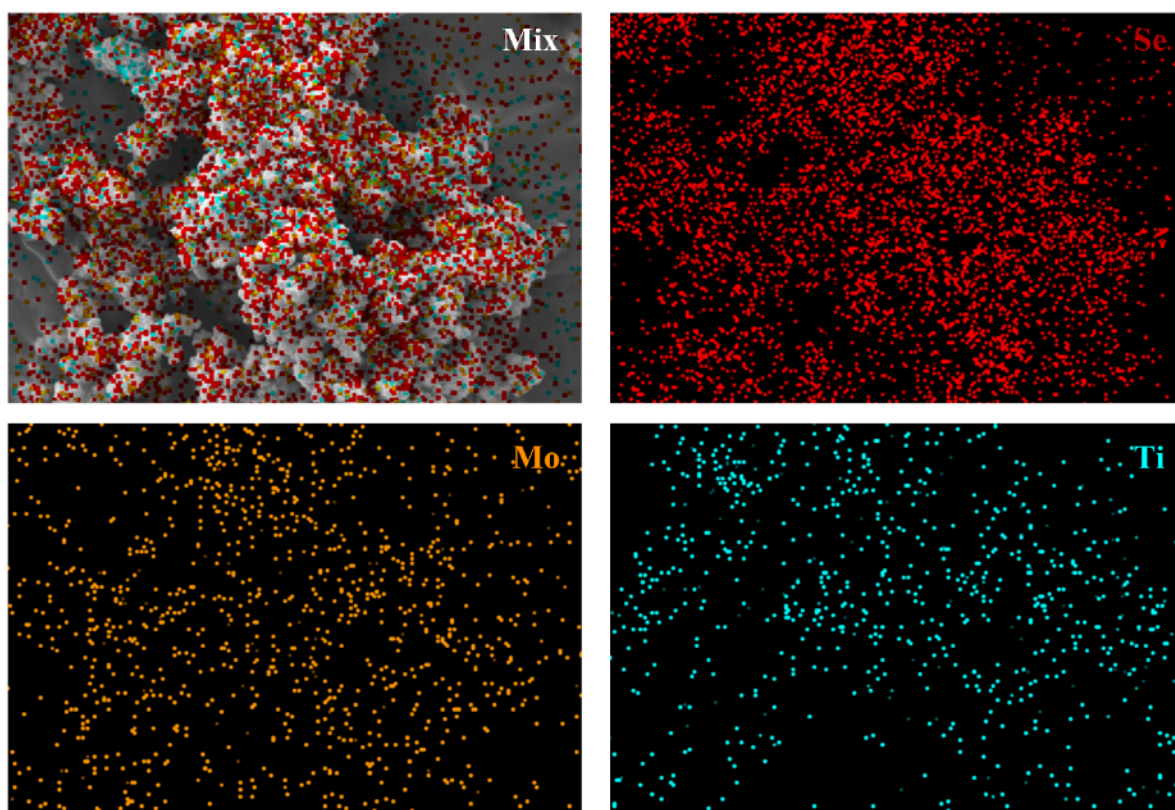
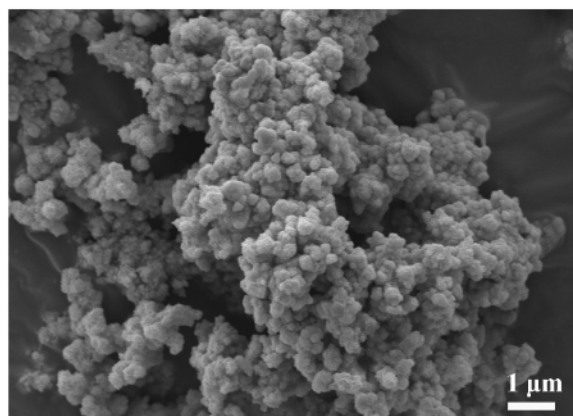


Fig. S13 EDX mappings of Ti-MoSe₂.

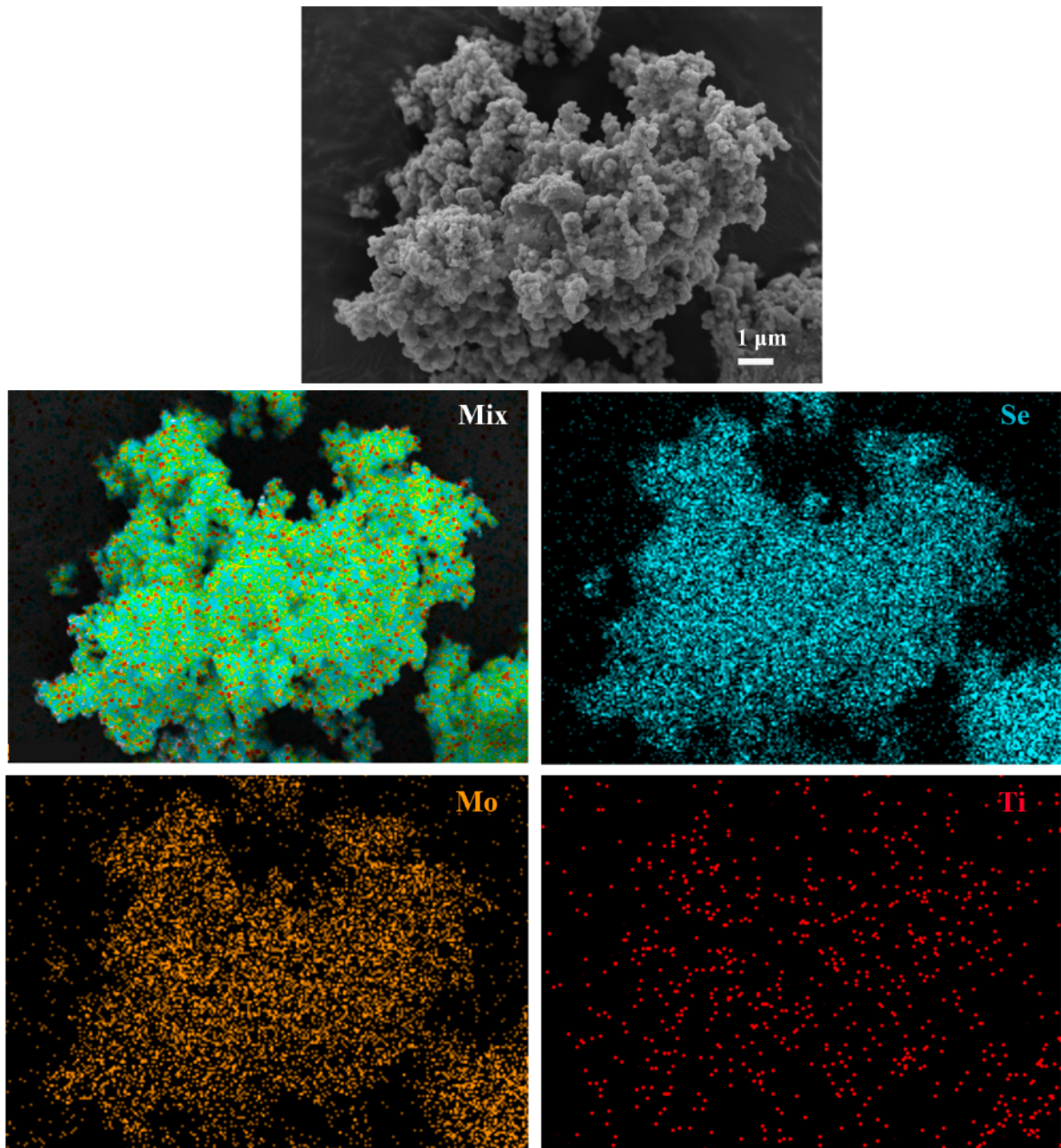


Fig. S14 EDX mappings of Ti-MoSe_{2-x}.

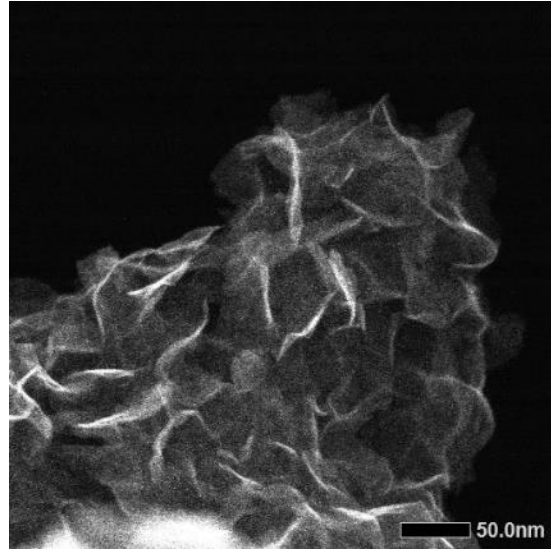


Fig. S15 STEM image of Ti-MoSe_{2-x}.

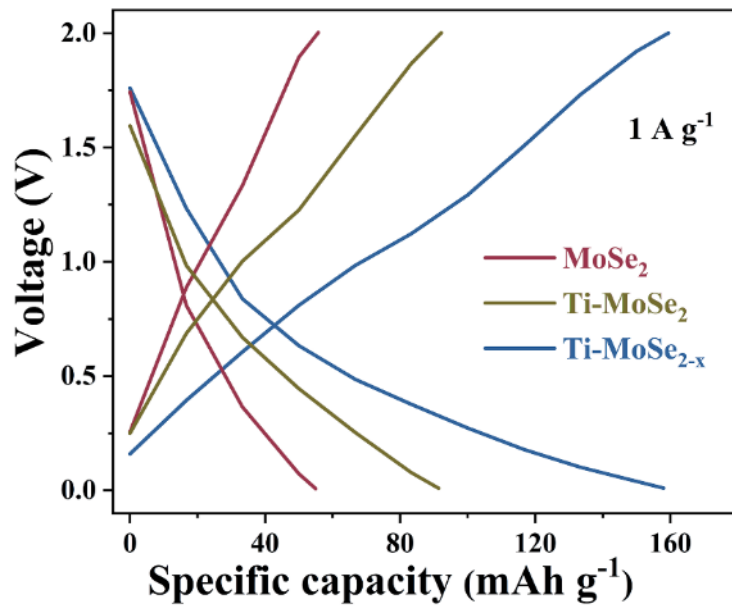


Fig. S16 Charge/discharge profiles at 1.0 A g⁻¹.

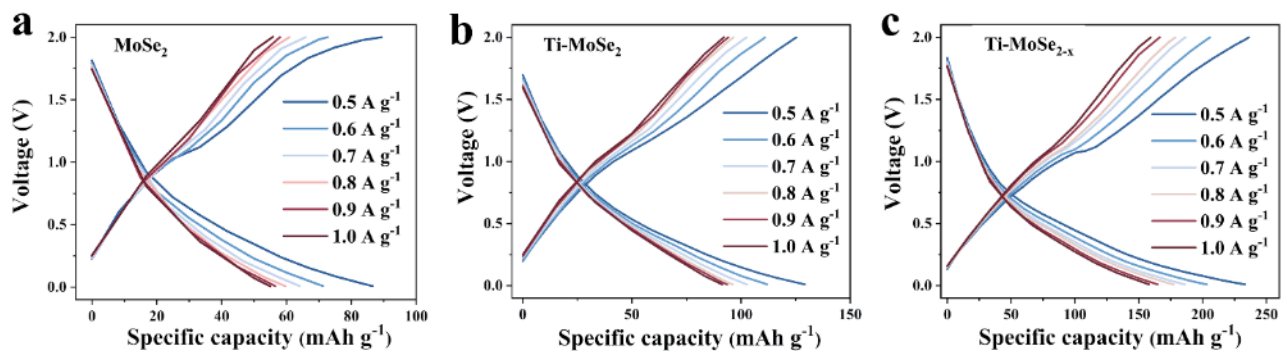


Fig. S17 Charge/discharge profiles of (a) MoSe₂, (b) Ti-MoSe₂, and (c) Ti-MoSe_{2-x} cathodes at current densities from 0.5 to 1.0 A g⁻¹.

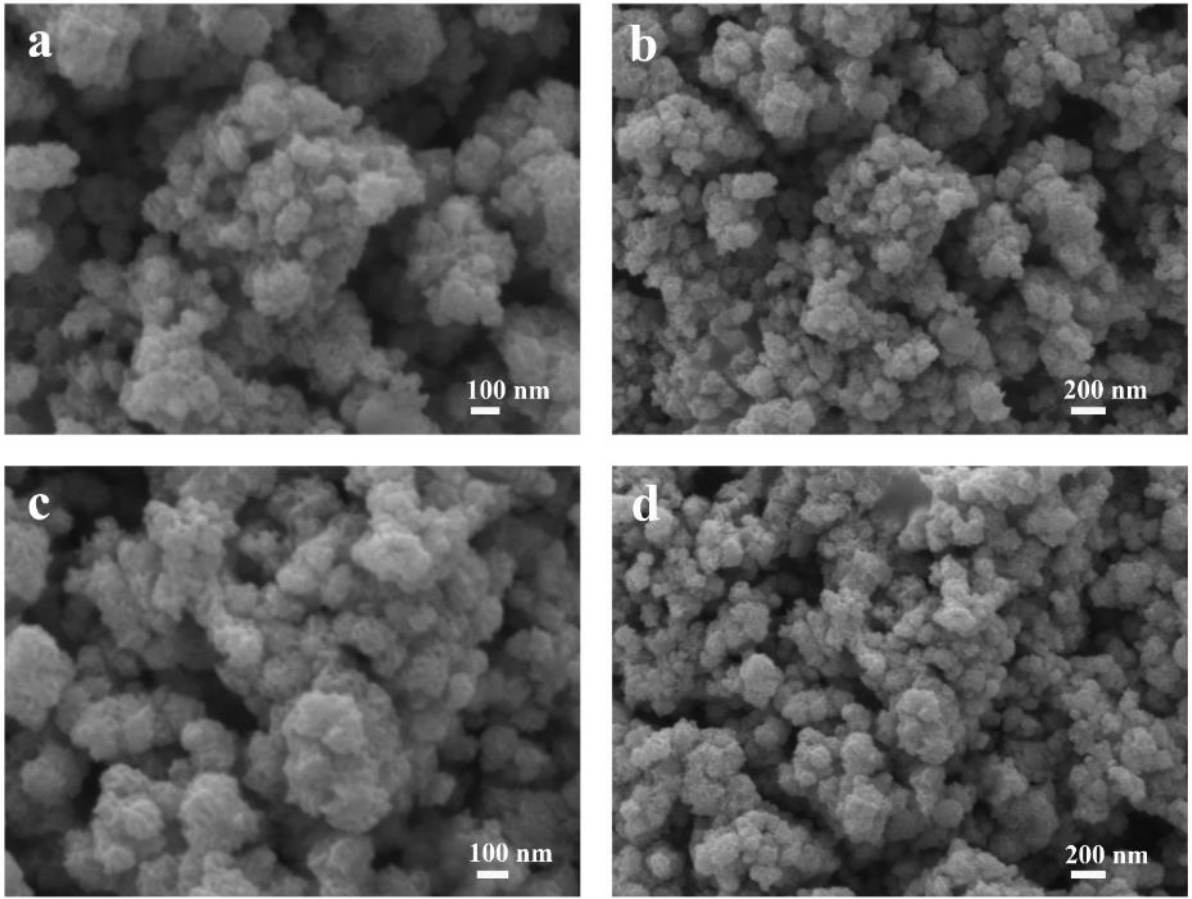


Fig. S18 FESEM images of MoSe_{2-x}.

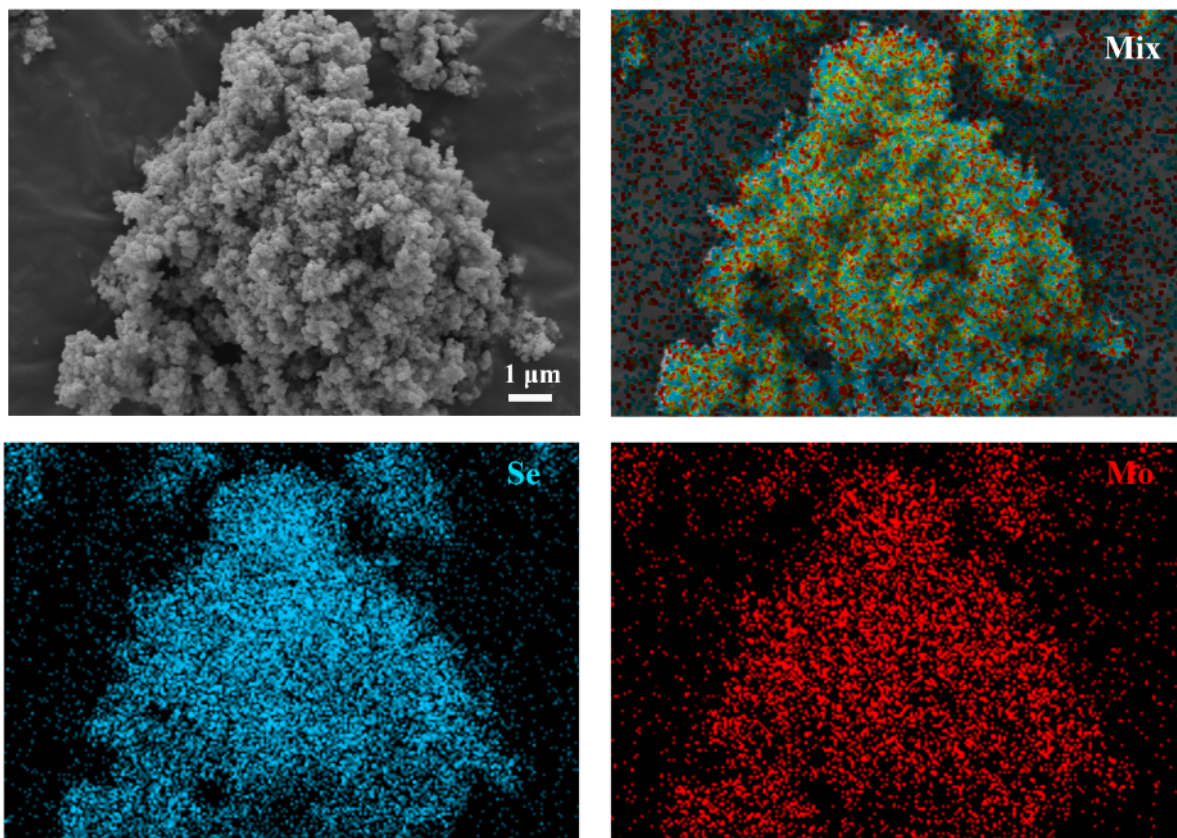


Fig. S19 EDX mappings of MoSe_{2-x}.

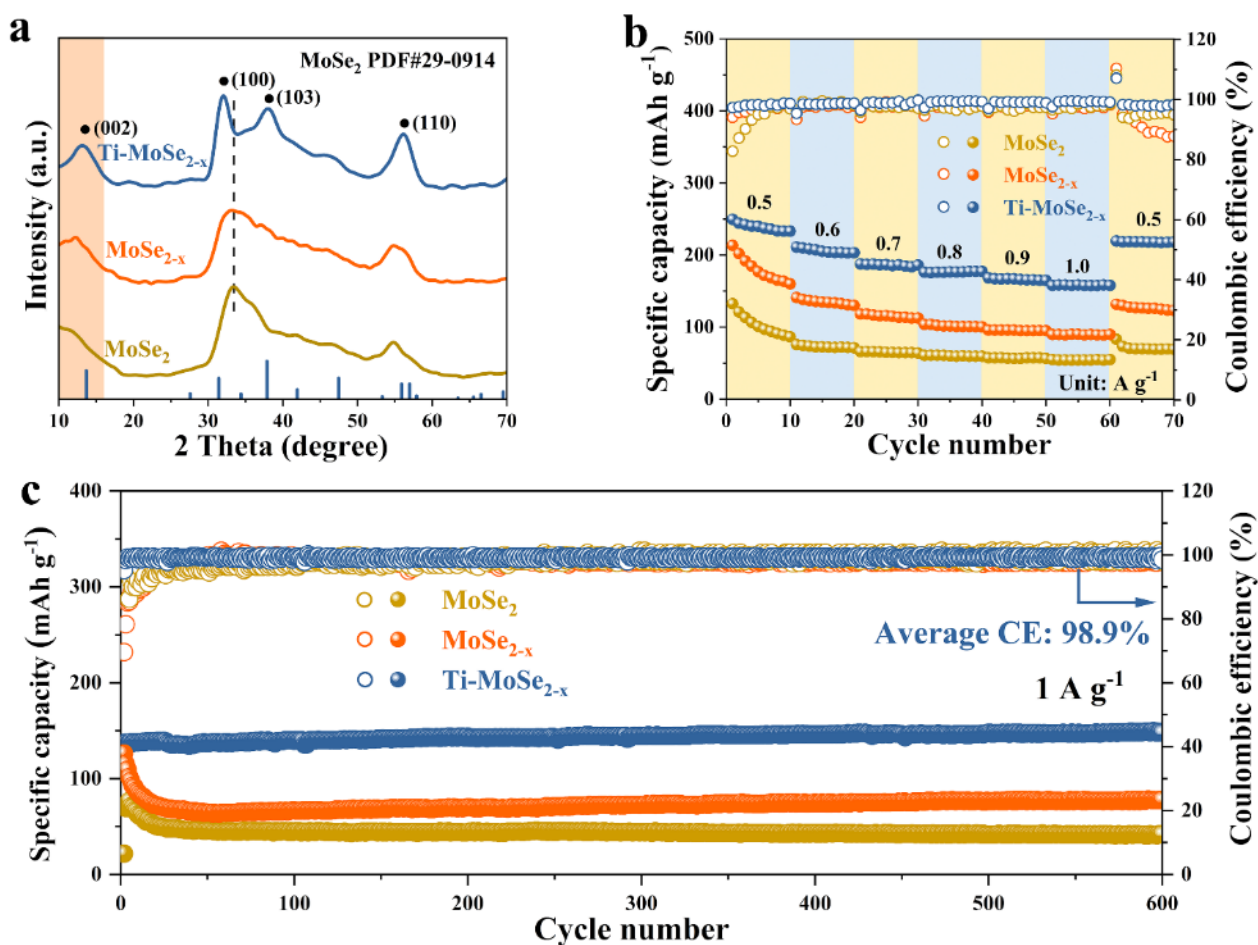


Fig. S20 (a) XRD patterns, (b) rate capacity, and (c) cycling stability of MoSe₂, MoSe_{2-x}, and Ti-MoSe_{2-x}.

According to the FESEM images (Fig. S18), the MoSe_{2-x} appears as nanoparticles with a rough surface, and the diameters are predominantly distributed between 100–150 nm. The morphology of MoSe_{2-x} is similar to that of MoSe₂, indicating that the microwave process has little effect on the morphology. The EDX mappings (Fig. S19) of MoSe_{2-x} demonstrate a uniform distribution of Mo and Se elements.

In the XRD pattern (Fig. S20a) of MoSe_{2-x}, a slight shift towards a lower angle is observed for the (100) characteristic peak, and the (002) peak is intensified compared to the pristine MoSe₂. This could be attributed to lattice distortion and an increase in layer spacing caused by the microwave process. Moreover, the electrochemical performance of MoSe_{2-x} has been tested and presented in Fig. S20b,c. In the rate performance tests, the MoSe_{2-x} displays specific capacities of 160 (10th), 130 (20th), 113 (30th), 100 (40th), 95 (50th), and 90 (60th) mAh g⁻¹ at 0.5, 0.6, 0.7, 0.8, 0.9, and 1.0 A g⁻¹, respectively. Compared to the pristine MoSe₂, the MoSe_{2-x} exhibits a significant enhancement in

capacity, yet it still suffers from severe capacity decay. In the cycling stability tests at 1.0 A g^{-1} , despite the MoSe_{2-x} demonstrating a high initial capacity of 126 mAh g^{-1} , the retention rate after 600 cycles is only 61%. Similar to MoSe_2 , the MoSe_{2-x} is observed to possess a drastic capacity decline within the first 30 cycles. The performance of MoSe_{2-x} can be summarized as having an increased capacity but still with an unstable structure. In contrast, the electrochemical performance of Ti-MoSe_2 (Fig. 3 and Fig. 4) shows high cycling stability and electron conductivity.

Therefore, according to the characterizations of MoSe_2 , MoSe_{2-x} , Ti-MoSe_2 , and Ti-MoSe_{2-x} , it can be deduced that the Ti element primarily enhances structural stability and electron conductivity as interlayer pillars, while the SVs mainly increase specific capacity by acting as additional active sites. Owing to the synergistic effects of Ti intercalation and SVs, the Ti-MoSe_{2-x} exhibits outstanding and comprehensive electrochemical performance.

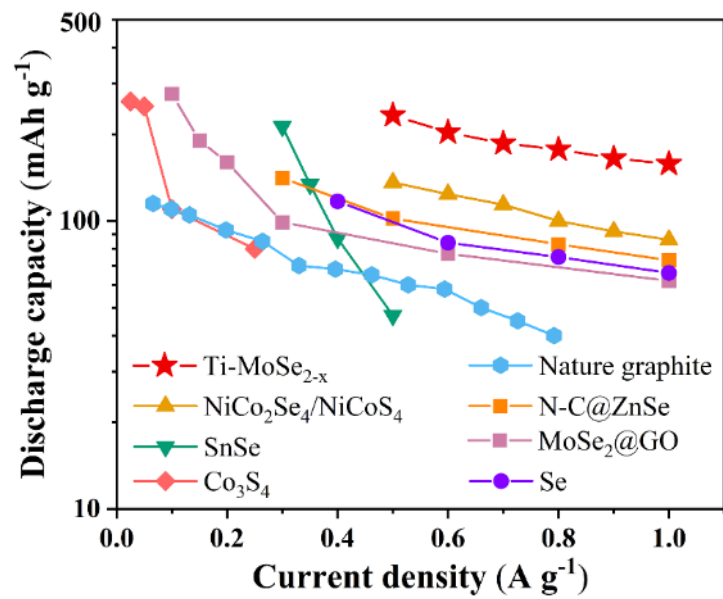


Fig. S21 Comparison of rate performance between Ti-MoSe_{2-x} and reported cathodes in ABs.

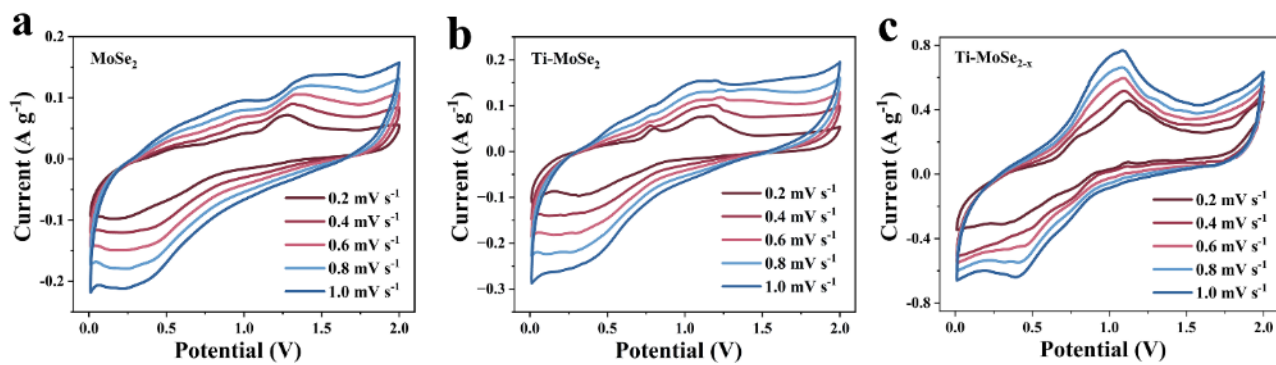


Fig. S22 CV curves of (a) MoSe₂, (b) Ti-MoSe₂, and (c) Ti-MoSe_{2-x} cathodes at scan rates from 0.2 to 1.0 mV s⁻¹.

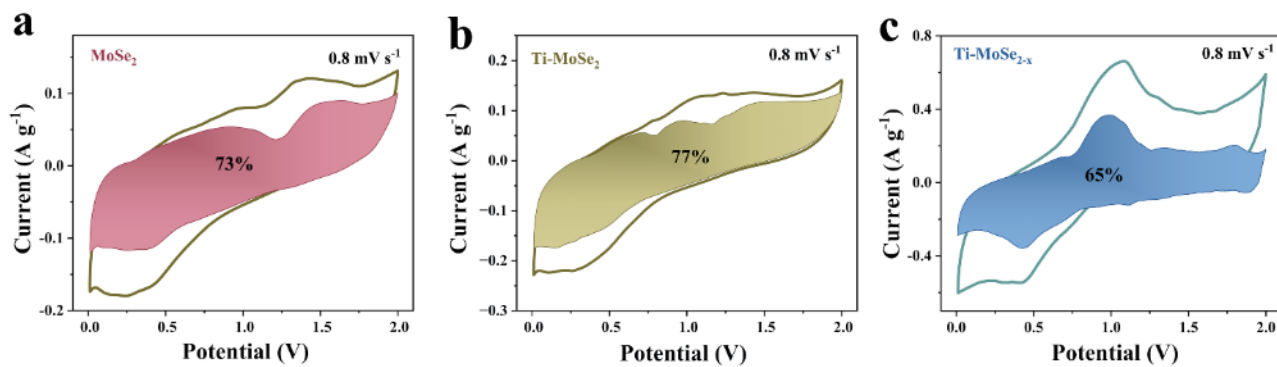


Fig. S23 Capacitive contribution of (a) MoSe_2 , (b) Ti-MoSe_2 , and (c) Ti-MoSe_{2-x} cathodes at a scan rate of 0.8 mV s^{-1} .

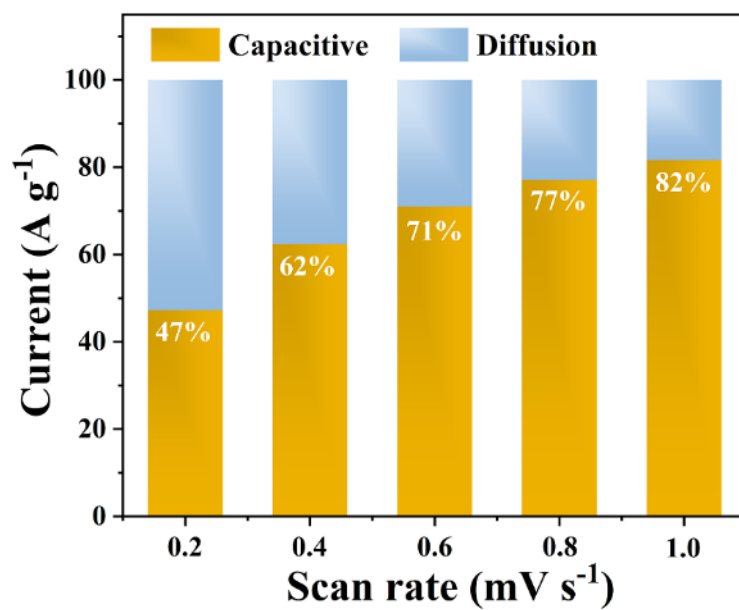


Fig. S24 Capacitive contributions of Ti-MoSe₂ at scan rates from 0.2 to 1.0 mV s⁻¹.

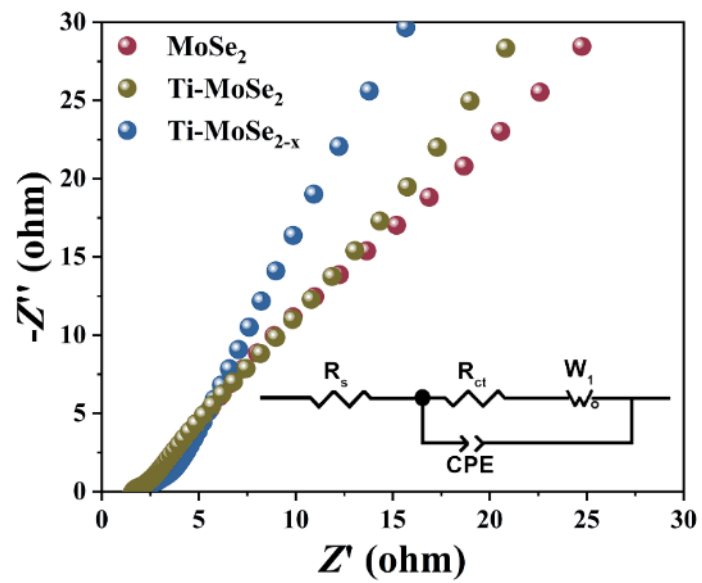


Fig. S25 Nyquist plots of MoSe₂, Ti-MoSe₂, and Ti-MoSe_{2-x} cathodes.

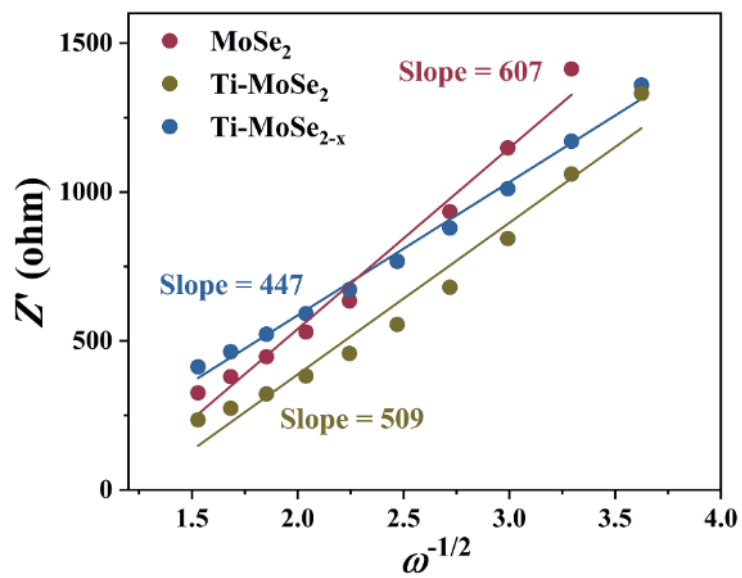


Fig. S26 Fitted plots of Z' and $\omega^{-1/2}$ for evaluating electronic diffusion capability.

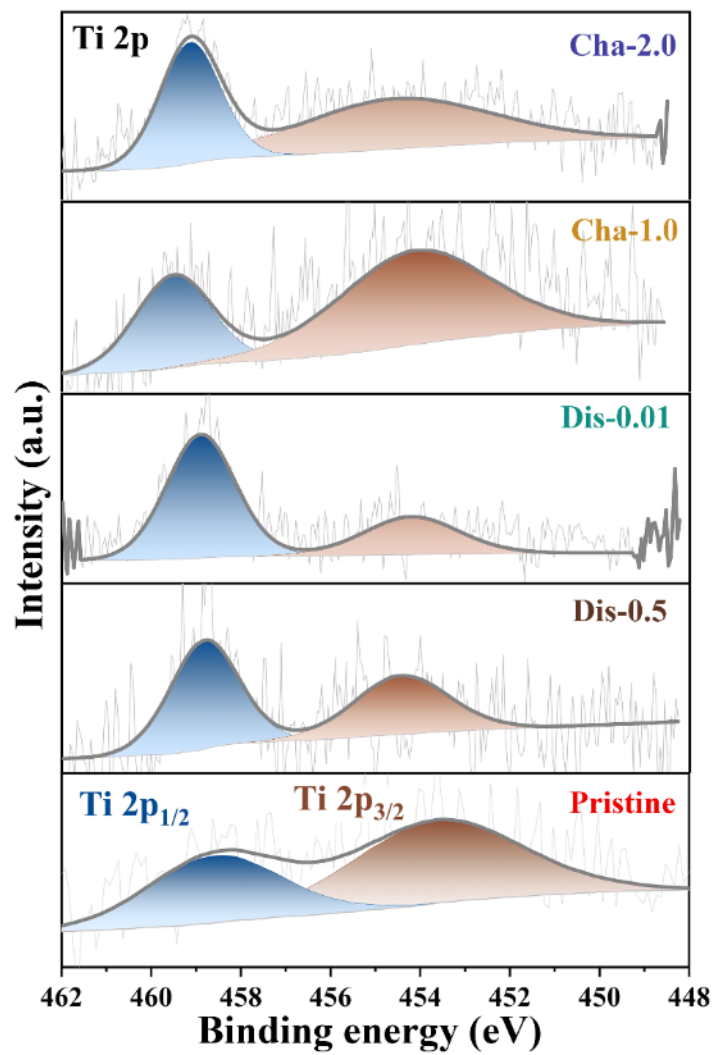


Fig. S27 Ex situ XPS spectrum of Ti 2p.

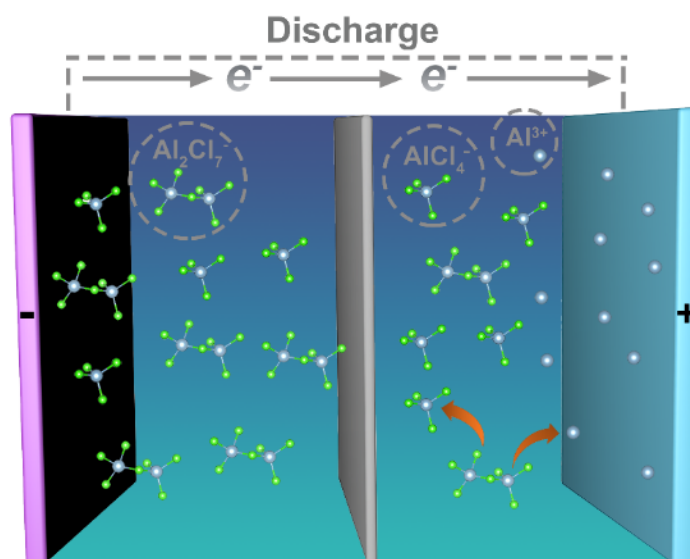


Fig. S28 Schematic diagram of the energy-storage mechanism of Ti-MoSe_{2-x} cathode in ABs.

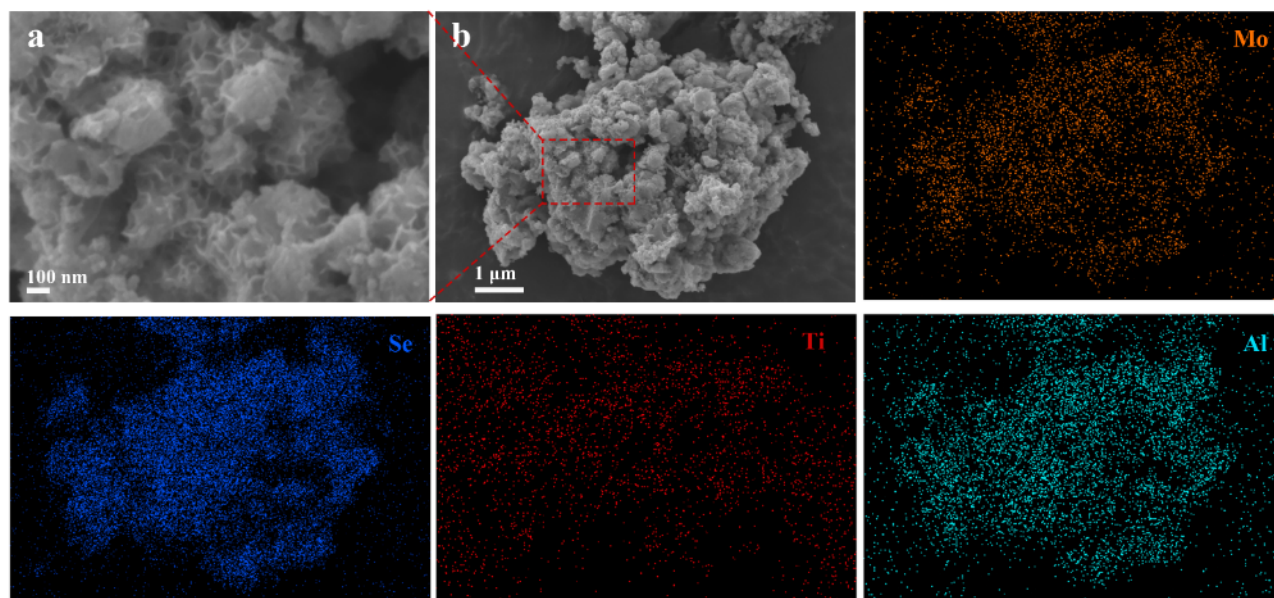


Fig. S29 (a) FESEM image and (b) EDX mappings of the Ti-MoSe_{2-x} cathode after 100 charged/discharged cycles.

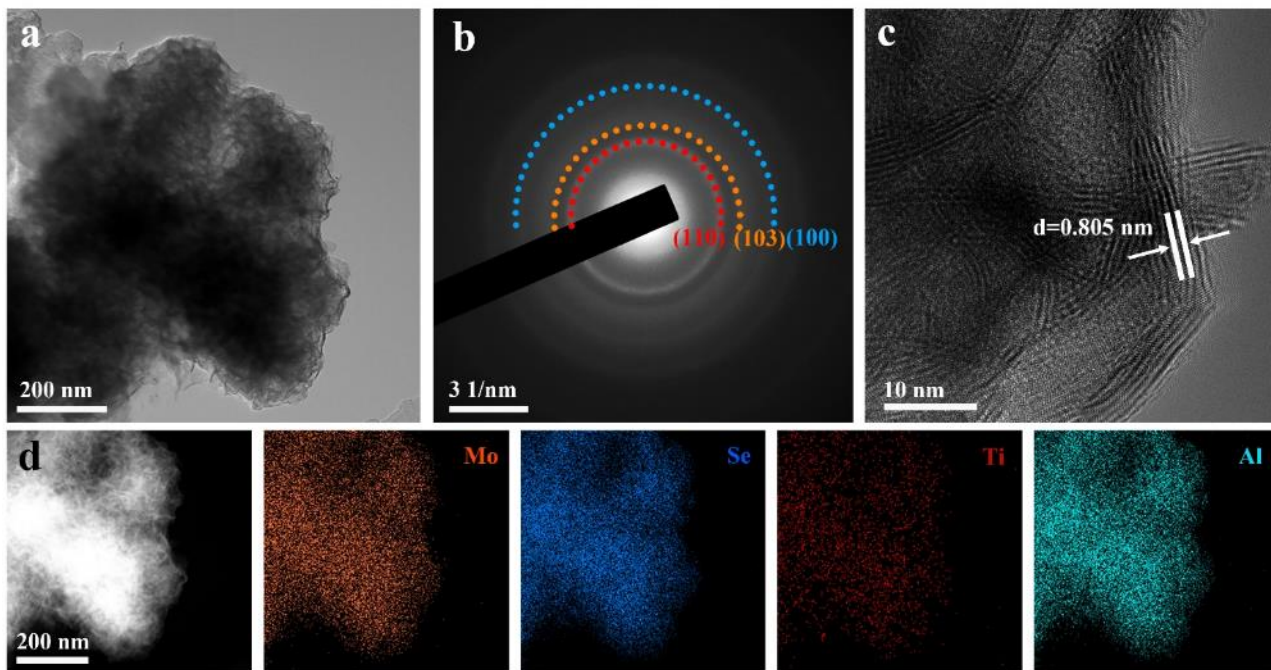


Fig. S30 (a) TEM image, (b) SAED pattern, (c) HRTEM image, and (d) EDX mappings of the Ti-MoSe_{2-x} cathode after 100 charged/discharged cycles.

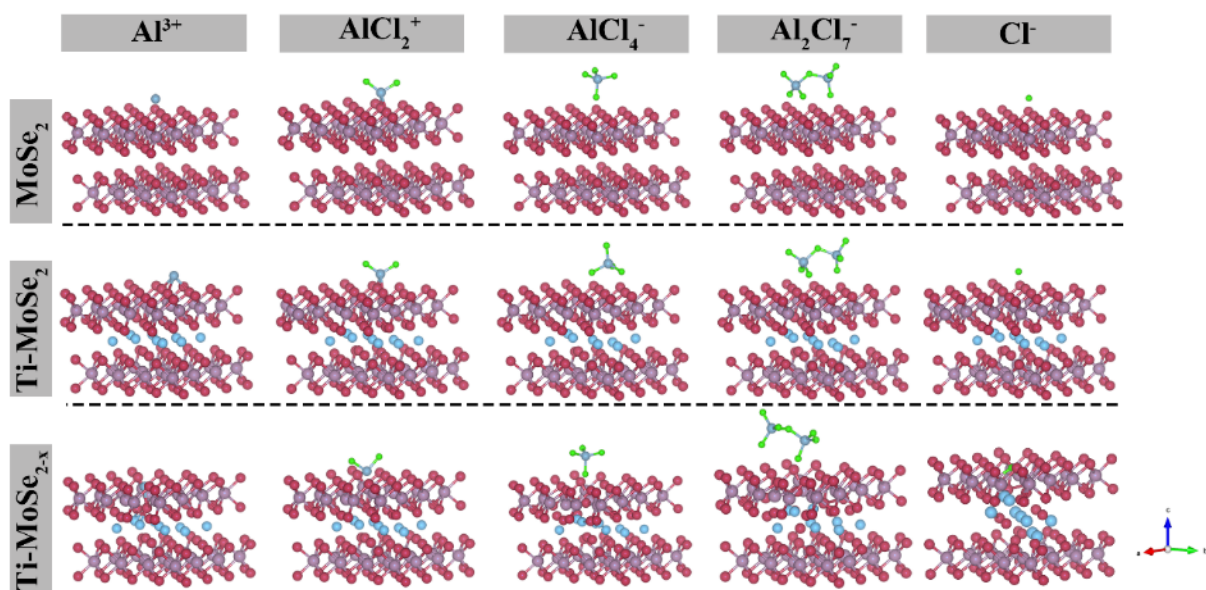


Fig. S31 Structural models of $MoSe_2$, $Ti-MoSe_2$, and $Ti-MoSe_{2-x}$ adsorbing active species.

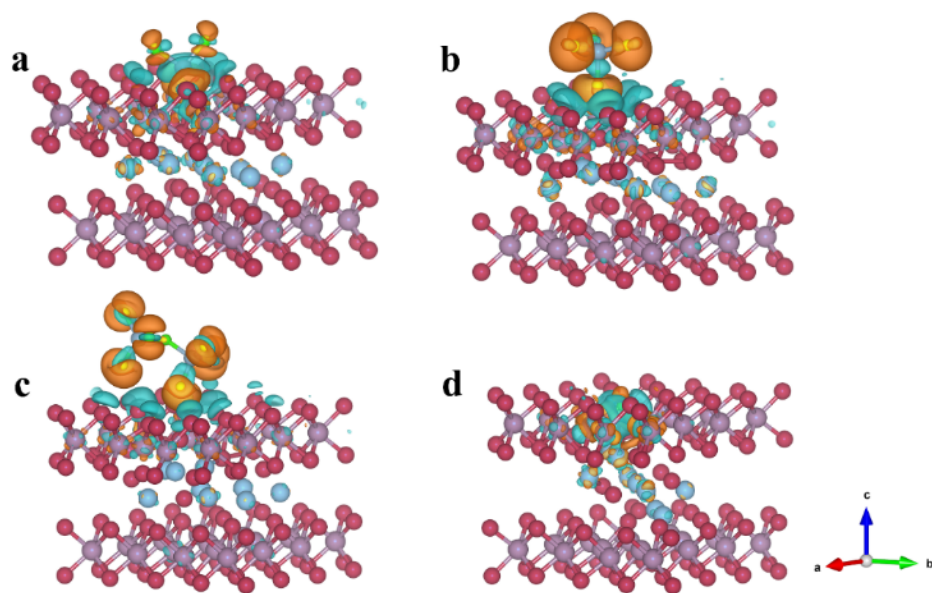


Fig. S32 Charge density differences of Ti-MoSe_{2-x} adsorbing (a) AlCl₂⁺, (b) AlCl₄⁻, (c) Al₂Cl₇⁻, and (d) Cl⁻.

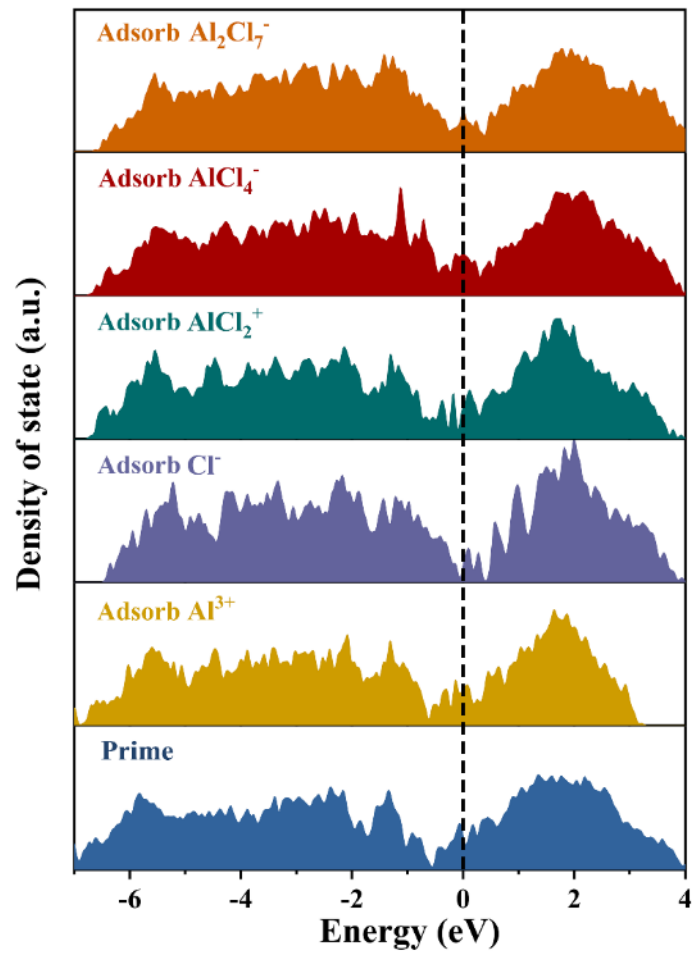


Fig. S33 DOS of Ti-MoSe_{2-x} adsorbing electrolyte ions.

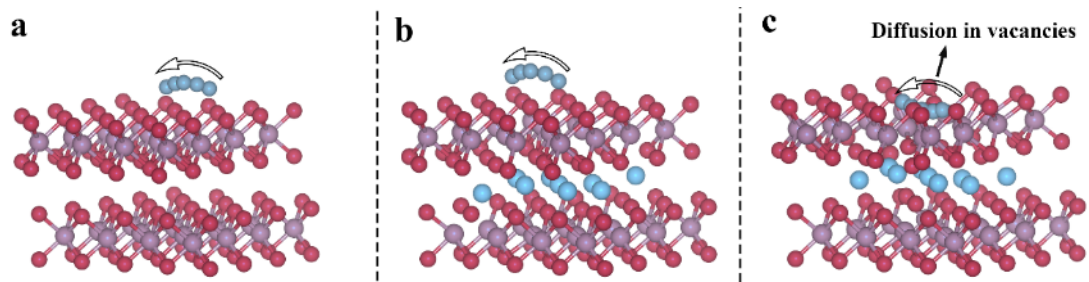


Fig. S34 Migration pathways of Al³⁺ on (a) MoSe₂, (b) Ti-MoSe₂, and (c) Ti-MoSe_{2-x}.

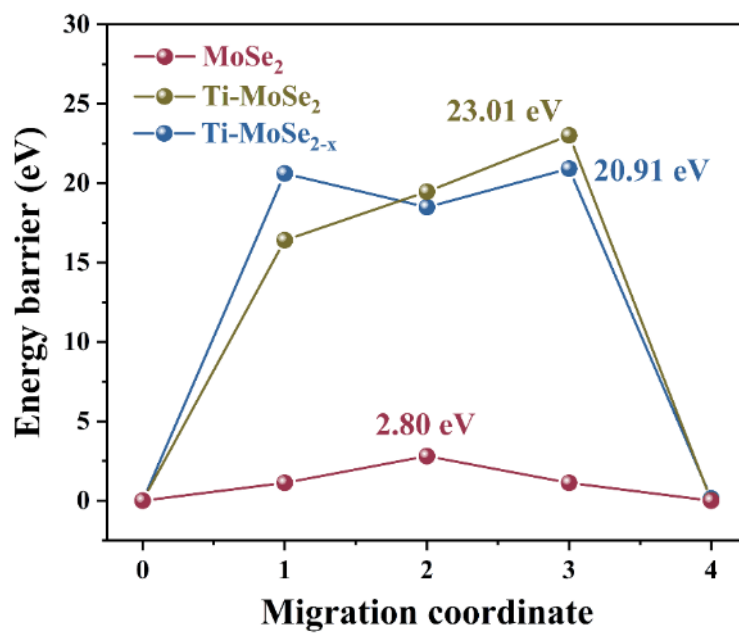


Fig. S35 Migration energy barriers of Al³⁺ between layers.

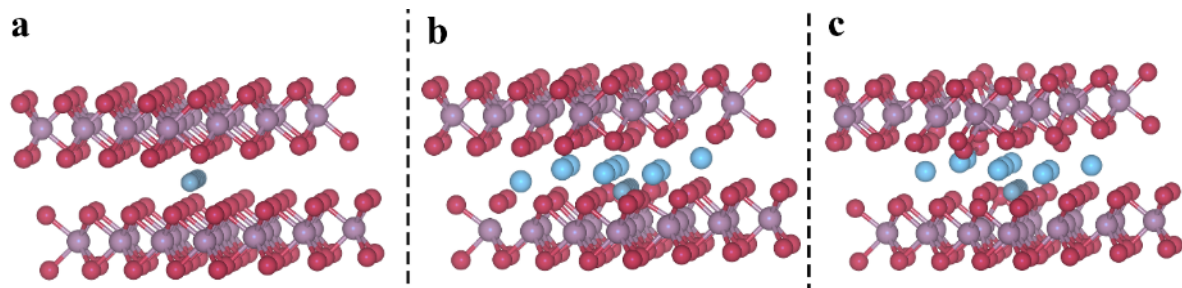


Fig. S36 Migration pathways of Al^{3+} in (a) MoSe_2 , (b) Ti-MoSe_2 , and (c) Ti-MoSe_{2-x} .

Table S1 ICP-OES results for Ti-MoSe_{2-x}.

Mo	Se	Ti
36.89 wt%	60.83 wt%	0.74 wt%

Table S2 Comparison of electrochemical performance between Ti-MoSe_{2-x} and reported cathodes.

Strategy	Capacity (mAh g ⁻¹)	Cycle (number)	Current density (A g ⁻¹)	Reference
Ti-MoSe_{2-x}	148 136	600 2400	1 5	This work
CNS@MC	167	350	1	[<i>Adv. Funct. Mater.</i> 2024 , 34, 2315603]
Expanded graphite	144	100	0.1	[<i>Carbon</i> 2024 , 223, 119016]
PVBPX	133	100	0.2	[<i>Angew. Chem.</i> 2023 , 135, e202216797]
SPANI	165	300	0.1	[<i>Adv. Mater.</i> 2022 , 34, 2106511]
FeF ₃ @EG	80	150	0.1	[<i>Adv. Energy Mater.</i> 2022 , 12, 2200959]
Li-VONB	162	300	0.05	[<i>Adv. Energy Mater.</i> 2022 , 12, 2201653]
Nb ₂ CTx	80	500	0.5	[<i>ACS Appl. Mater. Interfaces</i> 2022 , 14, 45254]
Activated carbon	80	1500	1	[<i>Carbon</i> 2022 , 191, 195]
Al _{2/3} Li _{1/3} Mn ₂ O ₄	93	1000	1	[<i>Energy Storage Mater.</i> 2022 , 53, 514]
V ₂ C@Se	119	1000	1	[<i>Energy Storage Mater.</i> 2022 , 46, 138]
CoSe ₂	148	500	0.5	[<i>Chem. Eng. J.</i> 2022 , 430, 133135]
Ti ₃ C ₂	134	500	0.5	[<i>J. Energy Chem.</i> 2022 , 74, 174]
(Fe,Mn,Ni,Zn,Mg) ₃ O ₄	163	200	1	[<i>Small</i> 2023 , 20, 2305998]
S-MoS ₂	129	1000	1	[<i>J. Mater. Chem. A</i> 2023 , 11, 15509]
Co ₃ Se ₄ /ZnSe	117	500	0.2	[<i>ACS Appl. Mater. Interfaces</i> 2023 , 15, 11906]
C4Q	102	500	0.2	[<i>J. Mater. Chem. A</i> 2023 , 11, 13527]
Co ₃ Sn ₂ @GO	114	100	0.2	[<i>Small</i> 2022 , 18, 2203236]
S-WSe ₂	110	1500	2	[<i>Small Methods</i> 2022 , 6, 2201281]
Bi ₂ Te ₃ /Sb ₂ Te ₃	101	3000	5	[<i>Energy Storage Mater.</i> 2021 , 38, 231]

Table S3 Adsorption energies of active species on MoSe₂, Ti-MoSe₂, and Ti-MoSe_{2-x}.

Systems	Al ³⁺	AlCl ₂ ⁺	AlCl ₄ ⁻	Al ₂ Cl ₇ ⁻	Cl ⁻
MoSe ₂	-1.34	-1.06	-1.21	-1.66	-1.20
Ti-MoSe ₂	-2.01	-1.71	-2.44	-1.50	-2.13
Ti-MoSe _{2-x}	-3.82	-2.94	-2.24	-2.52	-2.19

Table S4 Volume expansion degree of MoSe₂, Ti-MoSe₂, and Ti-MoSe_{2-x} adsorbing Al³⁺ and AlCl₄⁻.

Systems	MoSe₂ (%)	Ti-MoSe₂ (%)	Ti-MoSe_{2-x} (%)
Al³⁺	172	165	123
AlCl₄⁻	229	224	198